NSN 5961-01-059-4041

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-059-4041 **Inclosure Material:** Metal **Overall Length:** Between 0.160 inches and 0.180 inches **Terminal Length:** Between 0.985 inches and 1.015 inches **Overall Diameter:** Between 0.355 inches and 0.366 inches **Mounting Method: Terminal Terminal Circle Diameter:** 0.195 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 700.0 nonrepetitive peak reverse voltage and 600.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 100.00 amperes forward current, total rms watts and 100.00 amperes forward current, total rms torr **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Special Features:** Weapon system essential **Test Data Document:** 58260-13079910 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No